PIN Diode Single PIN Diode for Attenuator and RF Switch

Product Preview

NSDP301MX3

Low rs characteristics is enable to use high frequency applications. This PIN diode is designed to realize compact and efficient designs. NSDP301MX3 in a X3DFN2 miniature package enables designers to meet the challenging task of achieving higher efficiency and meeting reduced space requirements.

Features

- Low Series Resistance (rs = 1.3Ω typ.)
- Small Interterminal Capacitance (C = 0.33 pF typ.)
- Less Parasitic Components
- Small-sized Package X3DFN2
- Pb-Free, Halogen Free and RoHS Compliance

Typical Applications

- RF Attenuator
- RF Switch

MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Parameter	Symbol	Value	Unit
Reverse Voltage	V _R	80	V
Forward Current	IF	100	mA
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



ON Semiconductor®

www.onsemi.com

80 V, 100 mA rs = 1.3 Ω typ. PIN Diode





X3DFN2 CASE 152AF MARKING DIAGRAM

PIN 1

= Specific Device Code (Rotated 180°C)

M = Date Code

ORDERING INFORMATION

Device	Package	Shipping†
NSDP301MX3T5G	X3DFN2 (Pb-Free)	10,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NSDP301MX3

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Voltage	V_R	I _R = 1 μA	80			V
Reverse Current	I _R	V _R = 80 V			50	nA
Forward Voltage	V_{F}	I _F = 1 mA		0.78	0.81	V
Series Resistance	r _s	I _F = 10 mA, f = 100 MHz		1.3		Ω
Interterminal Capacitance	С	V _R = 0 V, f = 1 MHz		0.33		pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

NSDP301MX3

TYPICAL CHARACTERISTICS

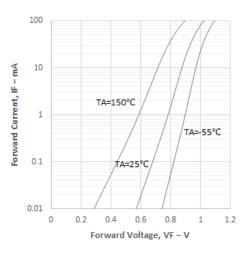


Figure 1. IF - VF

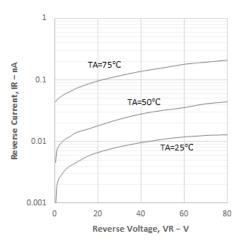


Figure 3. IR - VR

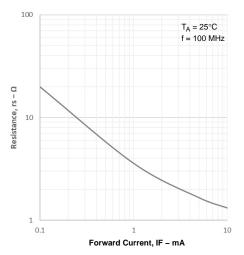


Figure 5. rs - IF

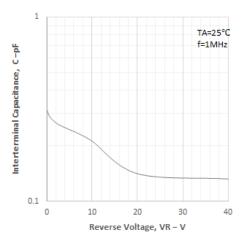


Figure 2. C - VR

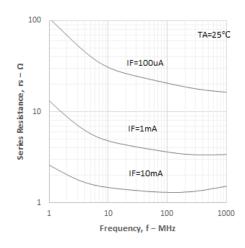


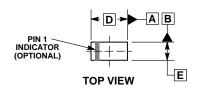
Figure 4. rs - f

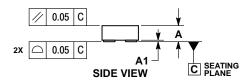
NSDP301MX3

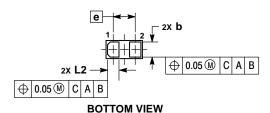
PACKAGE DIMENSIONS

X3DFN2, 0.62x0.32, 0.355P, (0201)

CASE 152AF ISSUE A





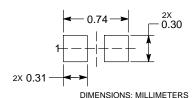


NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.25	0.33	
A1		0.05	
b	0.22	0.28	
D	0.58	0.66	
E	0.28	0.36	
е	0.355 BSC		
L2	0.17	0.23	

RECOMMENDED MOUNTING FOOTPRINT*



See Application Note AND8398/D for more mounting details

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and the are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor nakes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnif

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Email Requests to: orderlit@onsemi.com

TECHNICAL SUPPORT

North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada

ON Semiconductor Website: www.onsemi.com Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative